

KSD1222

Power Amplifier Applications High DC Current Gain

- Low Collector-Emitter Saturation Voltage
- Built in a Damper Diode at E-C
- Darlington TR
- Complement to KSB907



NPN Epitaxial Silicon Transistor

Absolute Maximum Ratings T_C=25°C unless otherwise noted

| Symbol | Parameter | Value | Units |
|------------------|--|------------|-------|
| V_{CBO} | Collector-Base Voltage | 60 | V |
| V_{CEO} | Collector-Emitter Voltage | 40 | V |
| V _{EBO} | Emitter-Base Voltage | 5 | V |
| I _C | Collector Current | 3 | А |
| I _B | Base Current | 0.3 | А |
| P _C | Collector Dissipation (T _C =25°C) | 15 | W |
| | Collector Dissipation (T _a =25°C) | 1 | W |
| T _J | Junction Temperature | 150 | °C |
| T _{STG} | Storage Temperature | - 55 ~ 150 | °C |

Electrical Characteristics T_C=25°C unless otherwise noted

| Symbol | Parameter | Test Condition | Min. | Тур. | Max. | Units |
|--------------------------------------|--------------------------------------|--|--------------|------|------|-------|
| BV _{CEO} | Collector-Emitter Breakdown Voltage | $I_C = 25 \text{mA}, I_B = 0$ | 40 | | | V |
| I _{CBO} | Collector Cut-off Current | $V_{CB} = 60V, I_{E} = 0$ | | | 20 | μΑ |
| I _{EBO} | Emitter Cut-off Current | $V_{EB} = 5V, I_{C} = 0$ | | | 2.5 | mA |
| h _{FE1} h _{FE2} | DC Current Gain | $V_{CE} = 2V, I_{C} = 1A$ $V_{CE} = 2V, I_{C} = 3A$ | 2000 1000 | | | |
| V _{CE} (sat) | Collector-Emitter Saturation Voltage | $I_C = 2A$, $I_B = 4mA$ | | | 1.5 | V |
| V _{BE} (sat) | Base-Emitter Saturation Voltage | $I_{C} = 2A, I_{B} = 4mA$ | | | 2 | V |
| t _{ON} | Turn On Time | $V_{CC} = 30V, I_{C} = 3A$ | | 0.1 | | μs |
| t _{STG} | Storage Time | $I_{B1} = -I_{B2} = 6mA$ | | 1 | | μs |
| t _F | Fall Time | $R_L = 10\Omega$ | | 0.2 | | μs |

Typical Characteristics

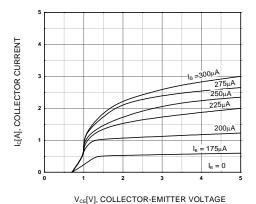


Figure 1. Static Characteristic

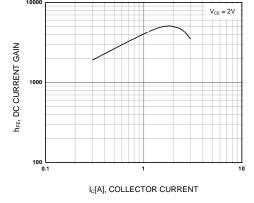


Figure 2. DC current Gain

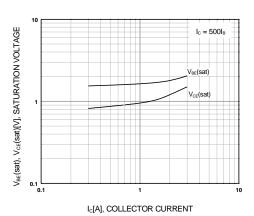


Figure 3. Base-Emitter Saturation Voltage Collector-Emitter Saturation Voltage

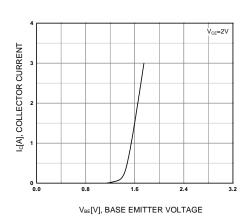


Figure 4. Base-Emitter On Voltage

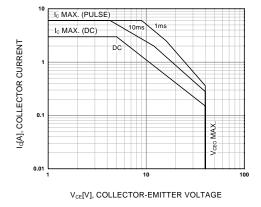


Figure 5. Safe Operating Area

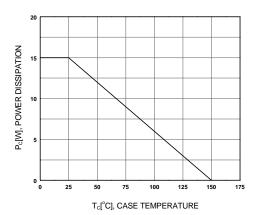
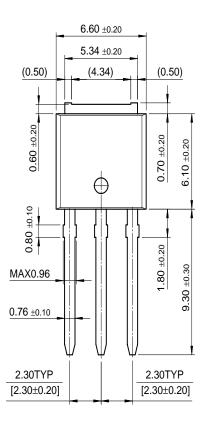


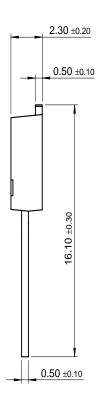
Figure 6. Power Derating

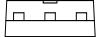
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Package Demensions

I-PAK







Dimensions in Millimeters

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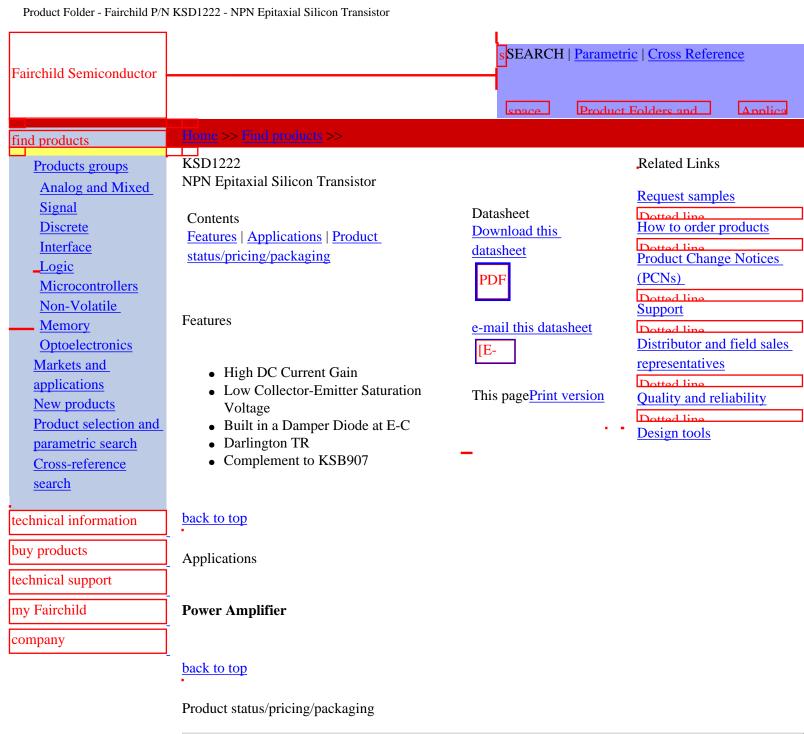
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| Product | Product status | Pricing* | Package type | Leads | Packing method |
|-----------|-----------------|----------|--------------|-------|----------------|
| KSD1222TU | Full Production | \$0.336 | TO-251(IPAK) | 3 | RAIL |

^{* 1,000} piece Budgetary Pricing

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